

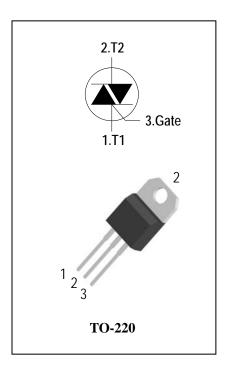
### 3 Quadrants High temperature Triacs

### **General Description**

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADT6CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current ( IT(RMS)= 6A )
- ♦ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



### **Absolute Maximum Ratings**

Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Denetitive Deals Off Chate Veltage	T: - 25°C	ADT6CH60	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	ADT6CH80	800	V
$I_{T(RMS)}$	R.M.S On-State Current	T <sub>C</sub> = 138 °C		6	Α
I <sub>TSM</sub>	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		70/74	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		28	A <sup>2</sup> s
.117.11	Critical rate of rise of on-state	F = 120 Hz Tj = 150°C $I_G = 2 \times I_{GT}$ , tr ≤ 100 ns		50	A/µs
dl/dt	current				
$I_{GM}$	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 150	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C



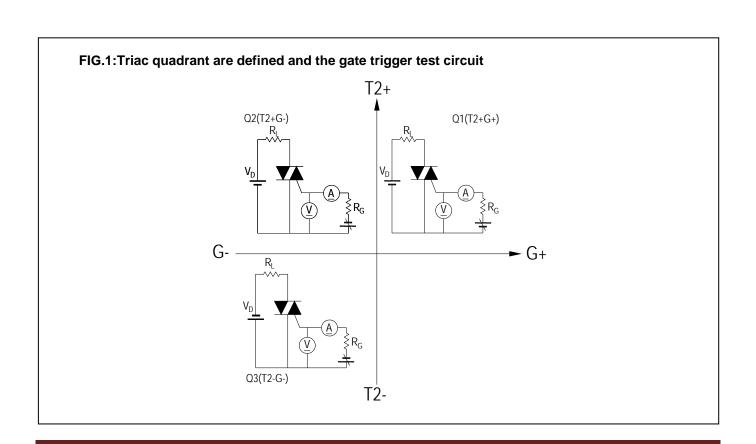


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### **Electrical Characteristics**( Tj = 25°C unless otherwise specified )

Symbol	Items		Conditions		ADT6CH60/80			Unit
					S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		$V_{DRM} = V_{RRM}$ , $Tj = 25$ °C	May	5		uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 150$ °C	Max.	2.7			mA
$V_{TM}$	Peak On-S	tate Voltage	$I_{TM} = 8.5A, t_p = 380 \mu s$	Max.	1.5		V	
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	Max		1.5			٧
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	20	45	60	mA
	Q1-Q3	Latabina Cumant	1 - 401	Max.	20	50	70	mA
IL	Q2	Latching Current	I <sub>G</sub> = 1.2 I <sub>GT</sub>		35	70	100	
dV/dt	Critical Rate of Rise of Off-State  Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	200	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		$V_D$ =400V Tj = 150°C (dl/dt)c=-2.6A/ms	Min.	1	15	20	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)		Max.	1.8		°C/W		
R <sub>th(j-a</sub> )	Junction to ambient			Max.	60			°C/W



# **ADV**

FIG.2: Maximum on-state power dissipation

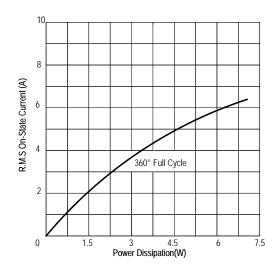


FIG.4: Maximum transient thermal impedance

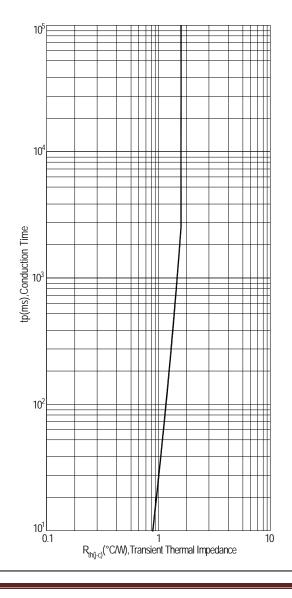


FIG.3: Typical RMS on-state current VS Allowable case Temperature

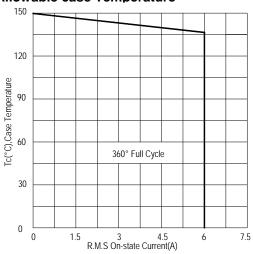


FIG.5: Rated surge on-state current (Non-Repetitive)

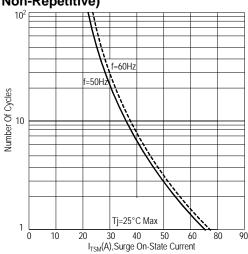


FIG.6: Gate trigger current VS Junction temperature

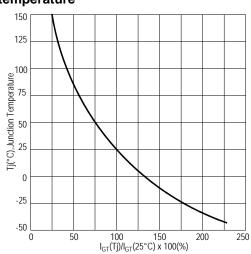




FIG.7:Holding current and Latching current VS Junction temperature

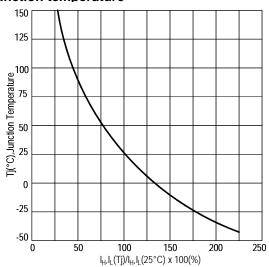


FIG.8: Gate trigger voltage VS Junction temperature

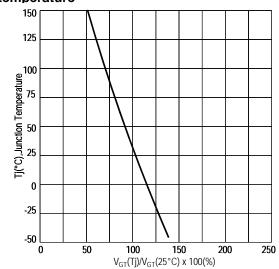
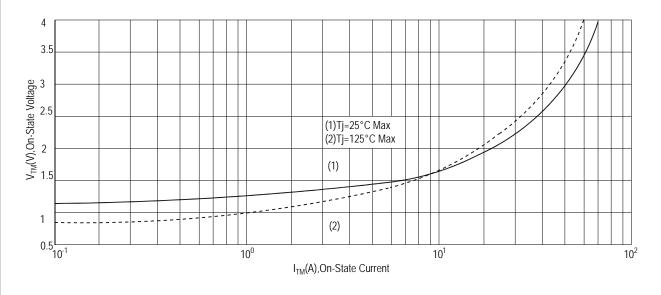


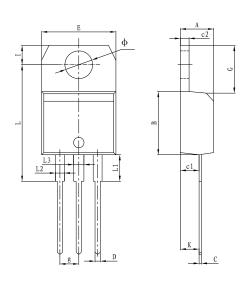
FIG.9: On-state characteristics(Max)



4 / 6 www.advsemi.com Feb,2013 -Rev.3.02

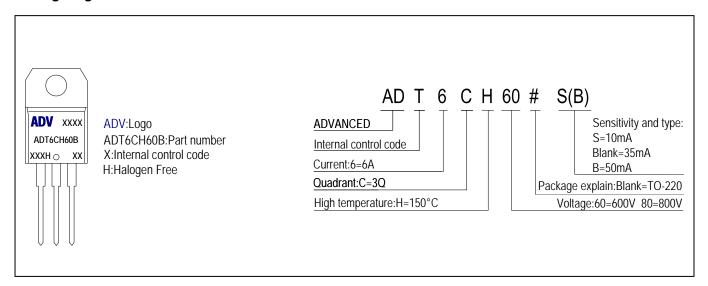


## PACKAGE MECHANICAL DATA TO-220 Package Dimension



	Dimer	nsions	Dimensions		
Symbol	In Milli	meters	In Inches		
	Min	Max	Min	Max	
Α	4.40	4.60	0.173	0.181	
В	9.00	9.30	0.354	0.366	
С	0.40	0.60	0.015	0.023	
c1	2.00	2.60	0.078	0.102	
c2	1.23	1.32	0.048	0.051	
D	0.70	1.00	0.027	0.039	
E	10.00	10.40	0.393	0.409	
g	2.40	2.70	0.094	0.106	
G	6.20	6.80	0.244	0.267	
I	2.65	2.95	0.104	0.116	
L	15.80	16.80	0.622	0.661	
L1	3.75		0.147		
L2	1.14	1.70	0.044	0.066	
L3	1.14	1.70	0.044	0.066	
Ф	Ф 3.60 3.90		0.141	0.153	
К	2.60	TYP	0.102TYP		

### **Making Diagram**



### **Ordering information**

Part number	Package	Marking Packing		Quantity		
ADT6CH60#	TO-220	ADT6CH60#	Tube	50pcs		
ADT6CH80#	TO-220	ADT6CH80#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



### ADT6CH60/80

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6 / 6 www.advsemi.com Feb,2013 -Rev.3.02